Unitized Semiconductor Devices - Page 1 of 1



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Inclosure Material: Metal
Overall Length:
Between 0.165 inches and 0.185 inches
Terminal Length:
0.500 inches
Overall Diameter:
Between 0.335 inches and 0.370 inches
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
Component Name And Quantity:
2 transistor
Mounting Method:
Terminal Circle Diameter:
0.200 inches
Semiconductor Material:
Silicon all transistor
Voltage Rating In Volts Per Characteristic:
30.0 breakdown voltage, collector-to-emitter, base open all transistor
Current Rating Per Characteristic:
30.00 milliamperes source cutoff current all transistor
Power Rating Per Characteristic:
400.0 milliwatts small-signal input power, common-collector absolute all transistor
Special Features:
Leads 4 and 8 omitted; transistor junction pattern arrangement: pnp
Terminal Type And Quantity:
6 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0